

Features

- Low $V_{CE(sat)}$ Trench-FS IGBT technology
- Positive temperature coefficient
- Including fast & soft recovery anti-parallel FWD
- High short circuit capability(10us)
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply

Maximum Ratings

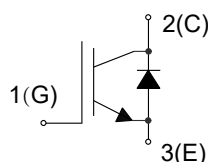
- Operating Junction Temperature Range : -40°C to $+175^{\circ}\text{C}$
- Storage Temperature Range: -55°C to $+150^{\circ}\text{C}$
- IGBT Thermal Resistance: 0.75°C/W Junction to Case
- Diode Thermal Resistance: 1.35°C/W Junction to Case
- Thermal Resistance: 40°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Collector-Emitter Voltage	V_{CE}	1200	V
DC Collector Current ⁽²⁾	I_C	$T_C=25^{\circ}\text{C}$ 30	A
		$T_C=100^{\circ}\text{C}$ 15	
Pulsed Collector Current ⁽³⁾ $V_{GE}=15\text{V}$	I_{CM}	60	A
Diode Forward Current ⁽²⁾	I_F	$T_C=25^{\circ}\text{C}$ 30	A
		$T_C=100^{\circ}\text{C}$ 15	
Diode Pulsed Current ⁽³⁾	$I_{F,puls}$	60	A
Gate-Emitter Voltage	V_{GE}	± 20	V
Transient Gate-Emitter Voltage		± 30	
Short Circuit Withstand Time $V_{GE}=15\text{V}$, $V_{CC}=900\text{V}$, $V_{CEM} \leq 1200\text{V}$	t_{SC}	10	μs
Power Dissipation	$T_J=25^{\circ}\text{C}$	P_D	200
			W

Note:

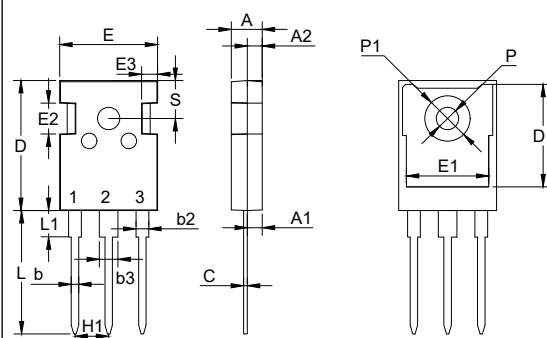
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. Limited by T_{Jmax} .
3. T_p limited by T_{Jmax} .

Internal Structure



Trench and Field Stop IGBT 1200V 15A

TO-247AB



DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.189	0.205	4.80	5.20	
A1	0.087	0.103	2.21	2.61	
A2	0.073	0.085	1.85	2.15	
b	0.039	0.055	1.00	1.40	
b2	0.075	0.087	1.91	2.21	
C	0.020	0.028	0.50	0.70	
D	0.815	0.839	20.70	21.30	
D1	0.640	0.663	16.25	16.85	
E	0.610	0.634	15.50	16.10	
E1	0.512	0.535	13.00	13.60	
E2	0.189	0.205	4.80	5.20	
E3	0.091	0.106	2.30	2.70	
L	0.772	0.796	19.62	20.22	
L1	-	0.169	-	4.30	
P	0.134	0.150	3.40	3.80	Φ
P1		0.287	-	7.30	Φ
S	0.242		6.15		TYP
H1	0.214		5.44		TYP
b3	0.110	0.126	2.80	3.20	

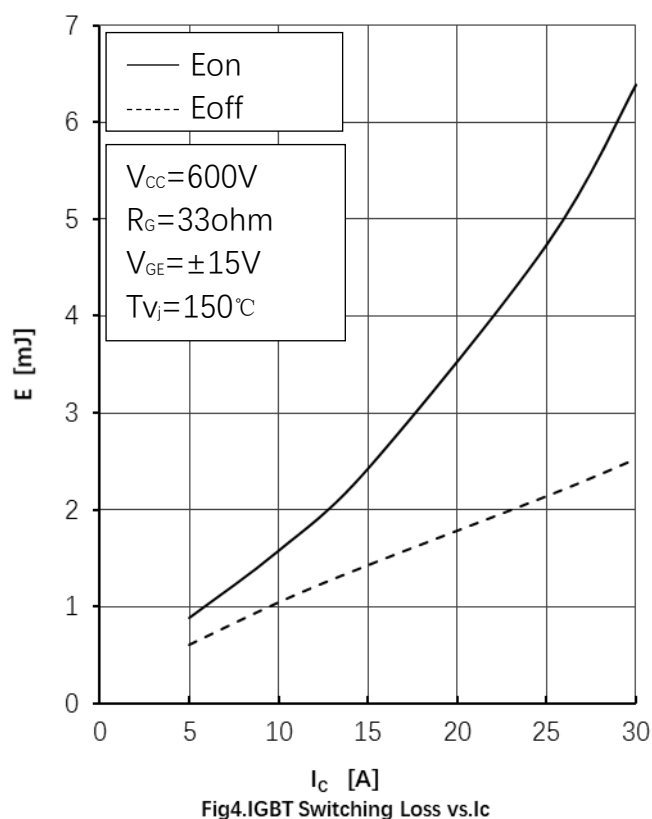
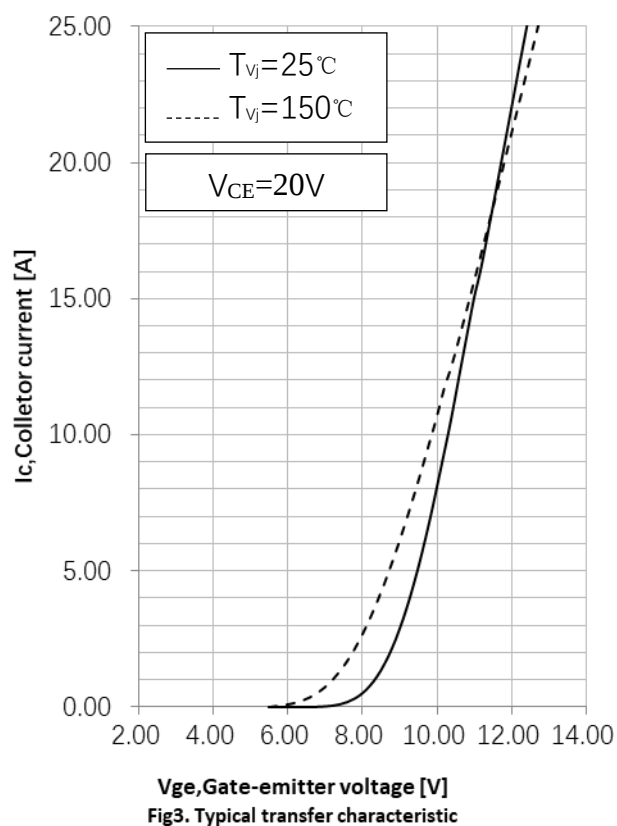
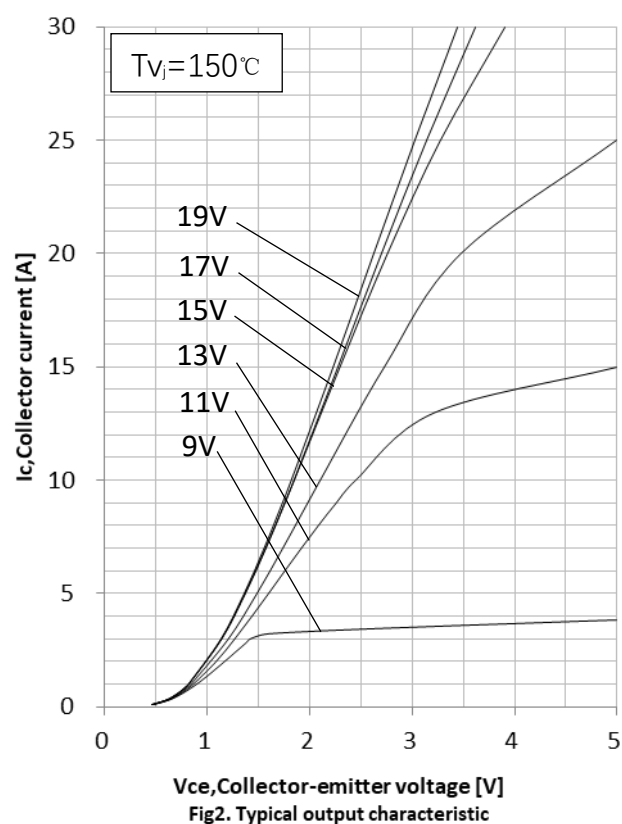
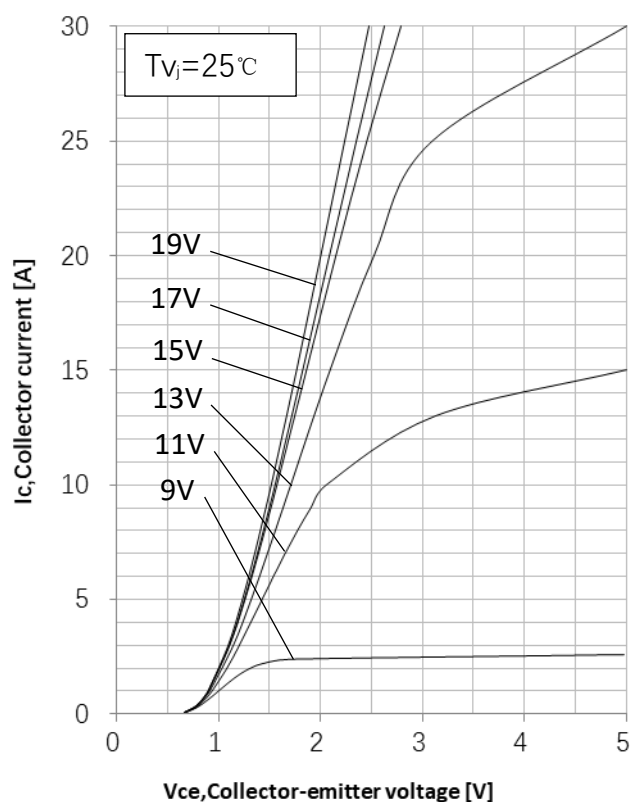
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Collector-Emitter Breakdown Voltage	$V_{(BR)CES}$	$V_{GE}=0V, I_C=250\mu A$	1200			V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V, I_C=15A, T_J=25^{\circ}C$		1.85	2.35	V
		$V_{GE}=15V, I_C=15A, T_J=125^{\circ}C$		2.20		
		$V_{GE}=15V, I_C=15A, T_J=150^{\circ}C$		2.30		
G-E Threshold Voltage	$V_{GE(th)}$	$I_C=500\mu A, V_{GE}=V_{CE}$	5.1	5.8	6.4	V
C-E Leakage Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_J=25^{\circ}C$			0.25	mA
		$V_{CE}=1200V, V_{GE}=0V, T_J=150^{\circ}C$			5.00	
G-E Leakage Current	I_{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$			100	nA
Dynamic Characteristics						
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1MHz$		1.2		nF
Reverse Transfer Capacitance	C_{res}			0.04		
Gate Charge	Q_g	$V_{CC}=960V, I_C=15A, V_{GE}=15V$		0.14		μC
Short Circuit Collector Current	I_{sc}	$V_{GE}=15V, t_{sc}\leq 10\mu s, V_{CC}=900V, T_J\leq 150^{\circ}C$		60		A
IGBT Switching Characteristics						
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=600V, I_C=15A, V_{GE}=-15\sim 15V, R_G=47\Omega$		45		ns
Rise Time	t_r			52		
Turn-Off Delay Time	$t_{d(off)}$			128		
Fall Time	t_f			186		
Turn-On Energy	E_{on}			1.5		mJ
Turn-Off Energy	E_{off}			0.9		
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=600V, I_C=15A, V_{GE}=-15\sim 15V, R_G=33\Omega, T_J=125$		50		ns
Rise Time	t_r			55		
Turn-Off Delay Time	$t_{d(off)}$			160		
Fall Time	t_f			135		
Turn-On Energy	E_{on}			2.2		mJ
Turn-Off Energy	E_{off}			1.3		
Turn-On Delay Time	$t_{d(on)}$	$V_{CC}=600V, I_C=15A, V_{GE}=-15\sim 15V, R_G=33\Omega, T_J=150$		52		ns
Rise Time	t_r			58		
Turn-Off Delay Time	$t_{d(off)}$			170		
Fall Time	t_f			138		
Turn-On Energy	E_{on}			2.4		mJ
Turn-Off Energy	E_{off}			1.45		

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Diode Static Characteristics						
Diode Forward Voltage	V _F	I _F =15A, T _J =25℃		2.00	2.40	V
		I _F =15A, T _J =125℃		1.80		
		I _F =15A, T _J =150℃		1.70		
Diode Dynamic Characteristics						
Diode Forward Voltage	V _{FM}	I _F =15A		1.90		V
Reverse Recovery Current	I _{rr}	V _R =600V, I _F =15A, di _F /dt=-240A/μs, T _J =25℃		7.5		A
Reverse Recovery Charge	Q _{rr}			1.8		μC
Reverse Recovery Energy	E _{rec}			0.60		mJ
Reverse Recovery Current	I _{rr}	V _R =600V, I _F =15A, di _F /dt=-240A/μs, T _J =125℃		9.0		A
Reverse Recovery Charge	Q _{rr}			2.4		μC
Reverse Recovery Energy	E _{rec}			0.9		mJ
Reverse Recovery Current	I _{rr}	V _R =600V, I _F =15A, di _F /dt=-240A/μs, T _J =150℃		9.5		A
Reverse Recovery Charge	Q _{rr}			2.6		μC
Reverse Recovery Energy	E _{rec}			1.0		mJ

Curve Characteristics



Curve Characteristics

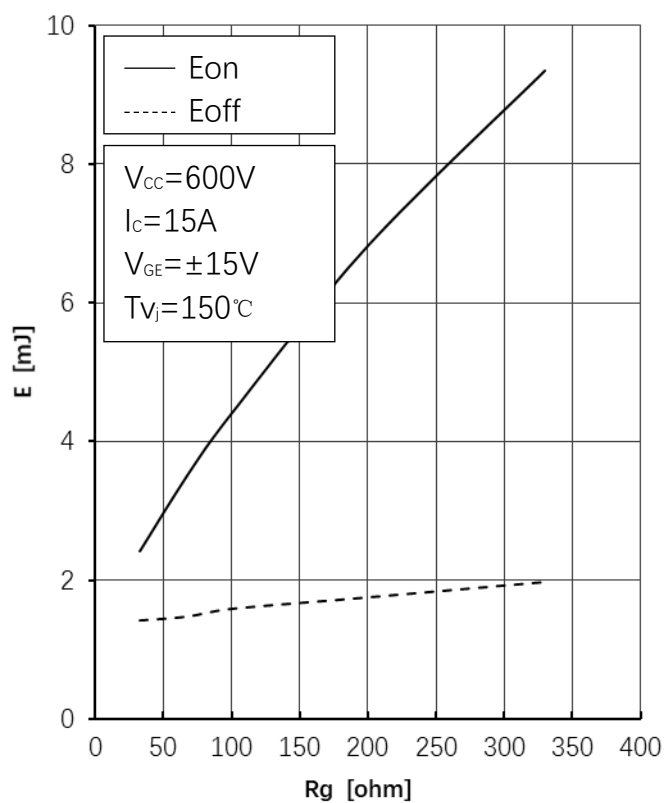


Fig5. IGBT Switching Loss vs. Rg

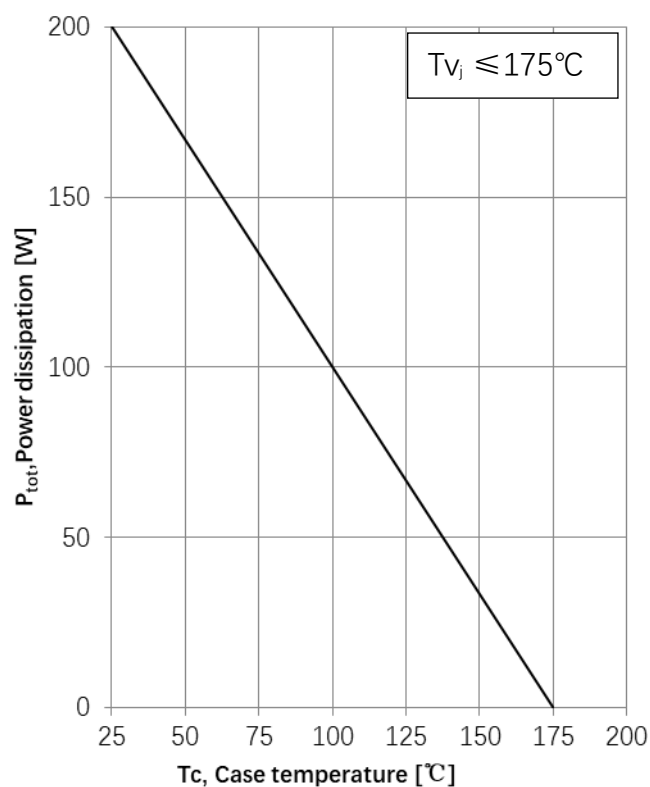


Fig6. Power dissipation as a function of case temperature

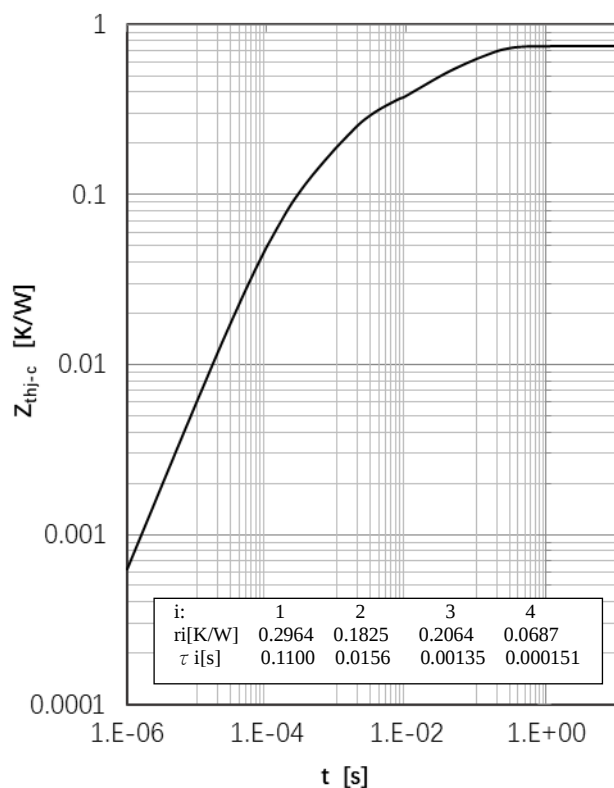


Fig 7. IGBT Transient Thermal Impedance

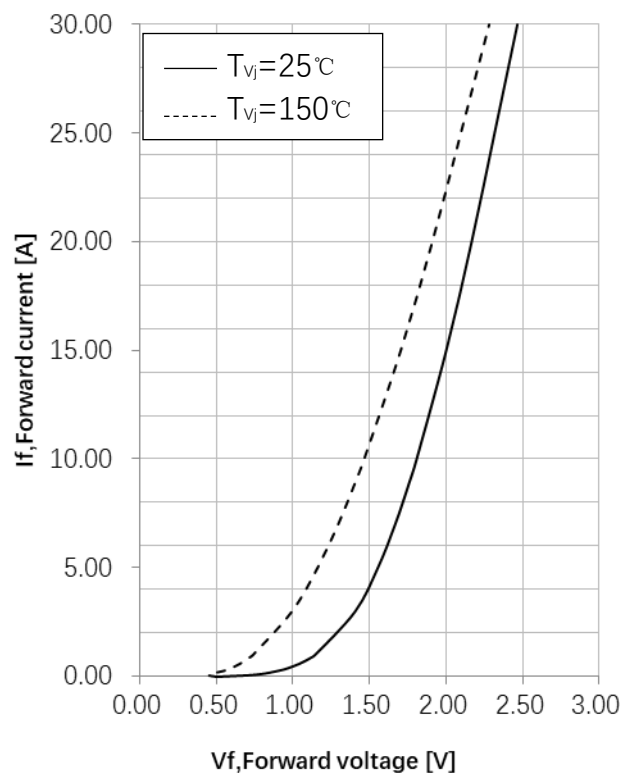


Fig8. diode forward current as a function of forward voltage

Curve Characteristics

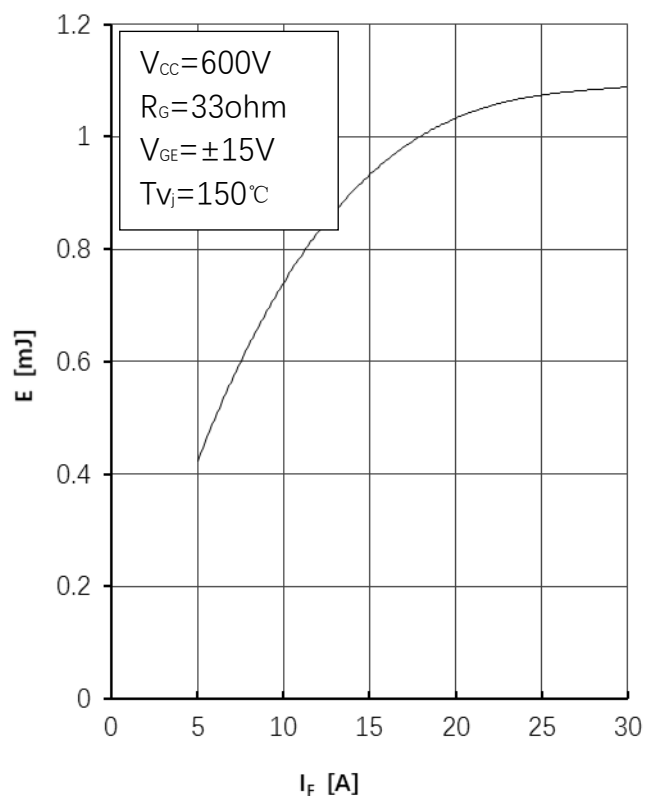


Fig9.Diode Switching Loss(E_{rec}) vs. I_F

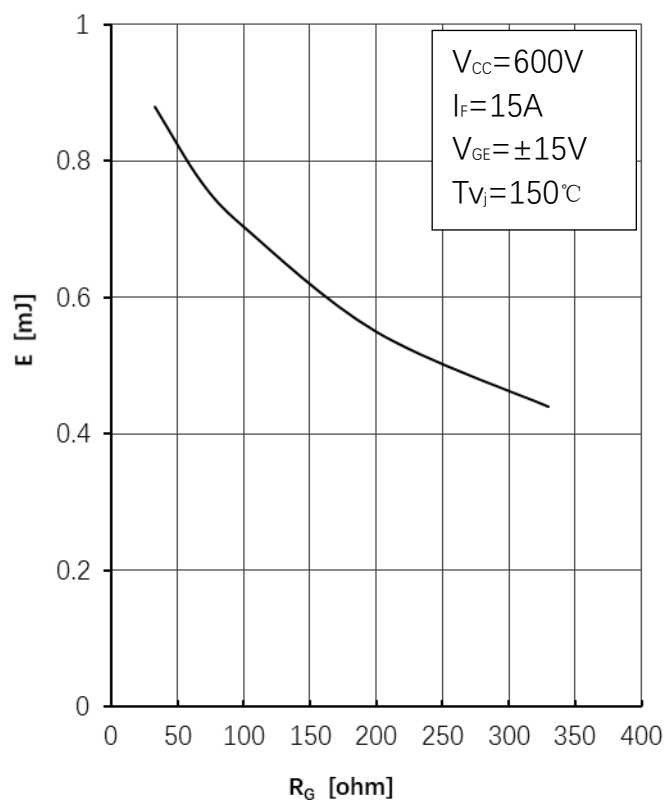


Fig10.Diode Switching Loss(E_{rec}) vs. R_G

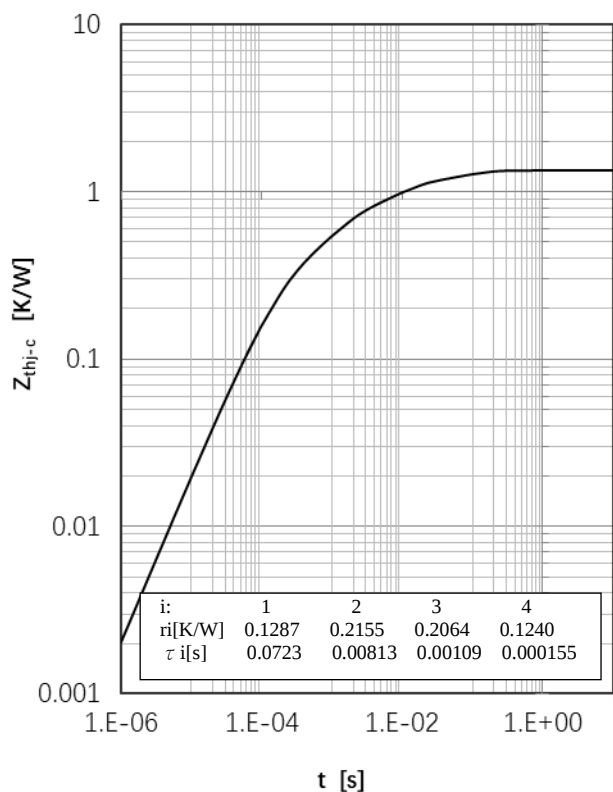


Fig11.Diode Transient Thermal Impedance

Ordering Information

Device	Packing
Part Number-BP	Tube: 30pcs/Tube, 1800pcs/Ctn

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